

PRODUCT SPECIFICATION

Model No : CSM-57211E/CSM-57221E

Descriptions:

- 2.0Inch Dot-Matrix Display
- 5*7 Array with X-Y Select.
- CSM-57211: Column Anode, Row Cathode
- CSM-57221: Column Cathode, Row Anode
- Emitting Color: Orange



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

CHINA SEMICONDUCTOR CORPORATION

Address:2FL. NO.909,Chung-Cheng Road,
Chung-Ho City Taipei Hsien,Taiwan.

Tel:886-2-2223-9696

Fax:886-2-2223-9377

OPTO PLUS TECHNOLOGIES CO.,LTD

Address:696 Shun jiang Rd.,Ji Shan St.Shaoxing,
ZheJiang,China

Tel:86-0575-88623888

Fax:86-0575-88623112

Model No : CSM-57211E/CSM-57221E

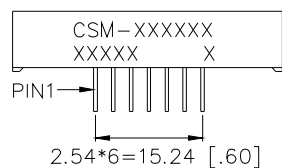
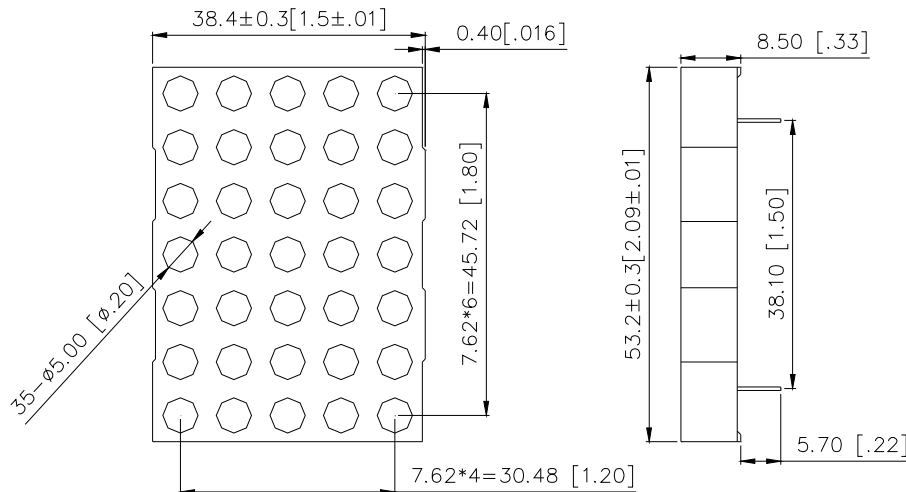
■ Features -

1. 2.0 inch (50.7mm) Matrix height.
2. Case mold type.
3. RoHs compliant.
4. Low power consumption.
5. Easy mounting on P.C. board or socket.

■ Device Selection Guide -

Part No.	Chip		Description	
	Material	Emitted Color	Column	Row
CSM-57211E	GaAsP	Orange	Anode	Cathode
CSM-57221E			Cathode	Anode

■ Package Dimensions -

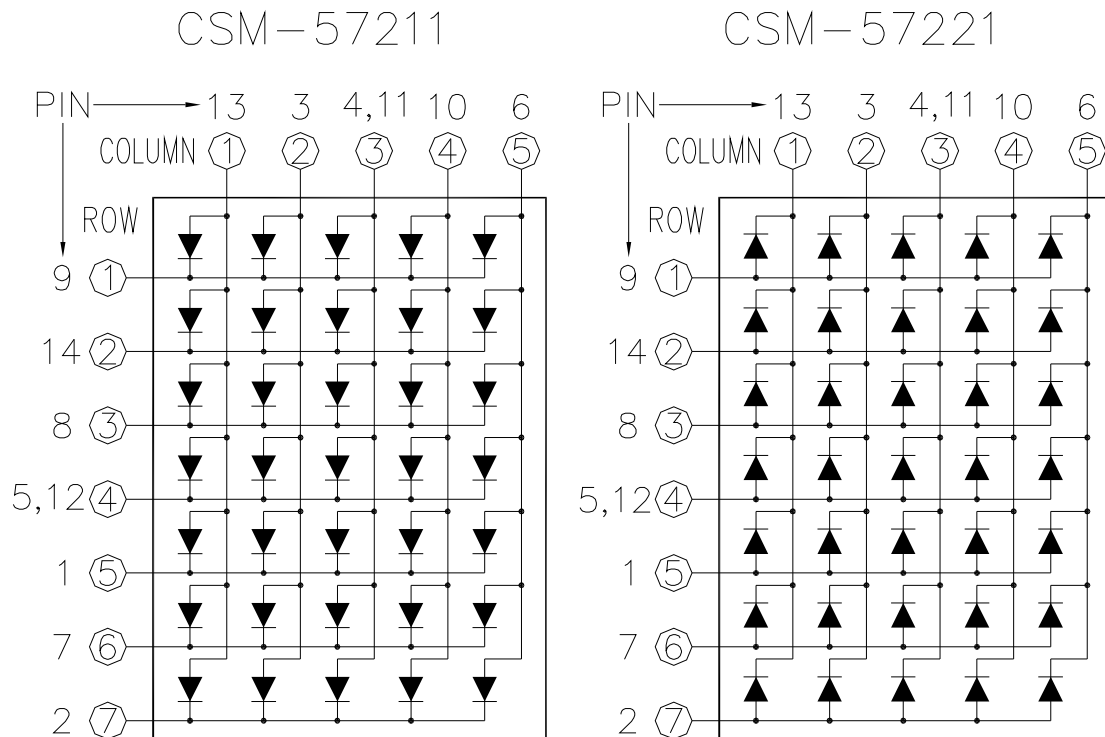


NOTE:

- 1 All pins are $\phi 0.5(.02)$.
- 2 All dimensions are in millimeters (inch), tolerance is $\pm 0.25 (.01)$ unless otherwise noted.

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Internal Circuit Diagrams -



CSM-57211				CSM-57221			
PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION	PIN NO.	FUNCTION
1	Cathode Row 5	8	Cathode Row 3	1	Anode Row 5	8	Anode Row 3
2	Cathode Row 7	9	Cathode Row 1	2	Anode Row 7	9	Anode Row 1
3	Anode Column 2	10	Anode Column 4	3	Cathode Column 2	10	Cathode Column 4
4	Anode Column 3	11	Anode Column 3	4	Cathode Column 3	11	Cathode Column 3
5	Cathode Row 4	12	Cathode Row 4	5	Anode Row 4	12	Anode Row 4
6	Anode Column 5	13	Anode Column 1	6	Cathode Column 5	13	Cathode Column 1
7	Cathode Row 6	14	Cathode Row 2	7	Anode Row 6	14	Anode Row 2

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■ Absolute Maximum Rating -

(Ta=25°C)

Parameter	Symbol	Rating	Unit
Power Dissipation Per Dice	P _{AD}	70	mW
Continuous Forward Current Per Dice	I _{AF}	25	mA
Peak Current Per Dice(duty cycle 1/10, 1kHz)	I _{PF}	90	mA
Derating Linear From 25°C Per Dice	-	0.33	mA/°C
Reverse Voltage Per Dice	V _R	5	V
Operating Temp.	T _{opr}	-35 ~ +85	°C
Storage Temp.	T _{stg}	-35 ~ +85	°C
Solder temperature 1/16 inch below seating plane for 3 seconds at 260°C			

■ Electro-optical Characteristics -

(Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward Voltage Per Segment	V _F	-	2.1	2.8	V	I _F =20mA
Luminous Intensity Per Segment	I _v	-	6500	-	ucd	I _F =10mA
Peak Emission Wavelength	λ _p	-	632	-	nm	I _F =20mA
Dominant Wavelength	λ _d	-	624	-	nm	I _F =20mA
Spectrum Radiation Bandwidth	Δλ	-	35	-	nm	I _F =20mA
Reverse Current	I _R	-	-	100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _{V-m}	-	-	2:1	-	I _p =80mA 1/16Duty

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Typical Electrical / Optical Characteristics Curves -

(Ta = 25°C Unless Otherwise Noted)

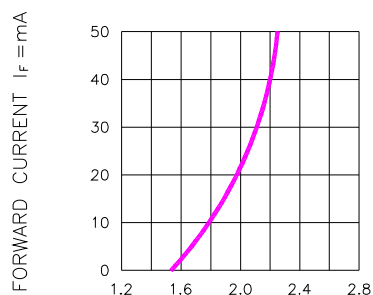


Fig.1 FORWARD CURRENT VS. FORWARD VOLTAGE

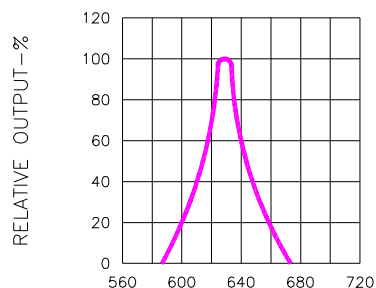


Fig.2 SPECTRAL RESPONSE

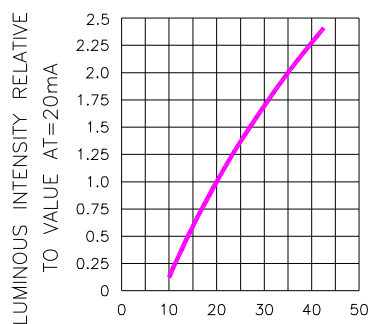


Fig.3 RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

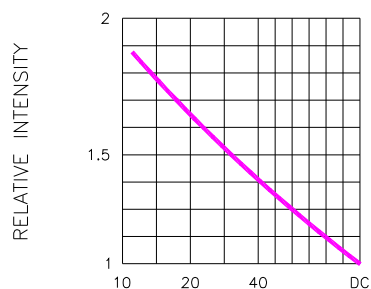


Fig.5 LUMINOUS INTENSITY VS. DUTY CYCLE

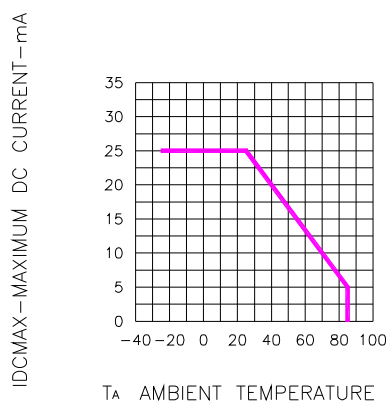


Fig.4 MAXIMUM ALLOWABLE DC CURRENT PER SEGMENT VS. A FUNCTION OF AMBIENT TEMPERATURE

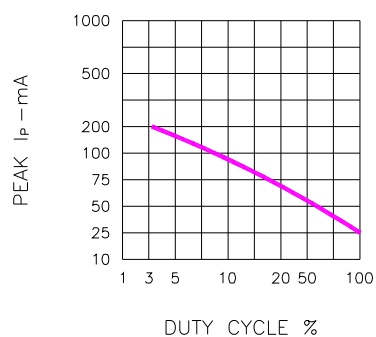


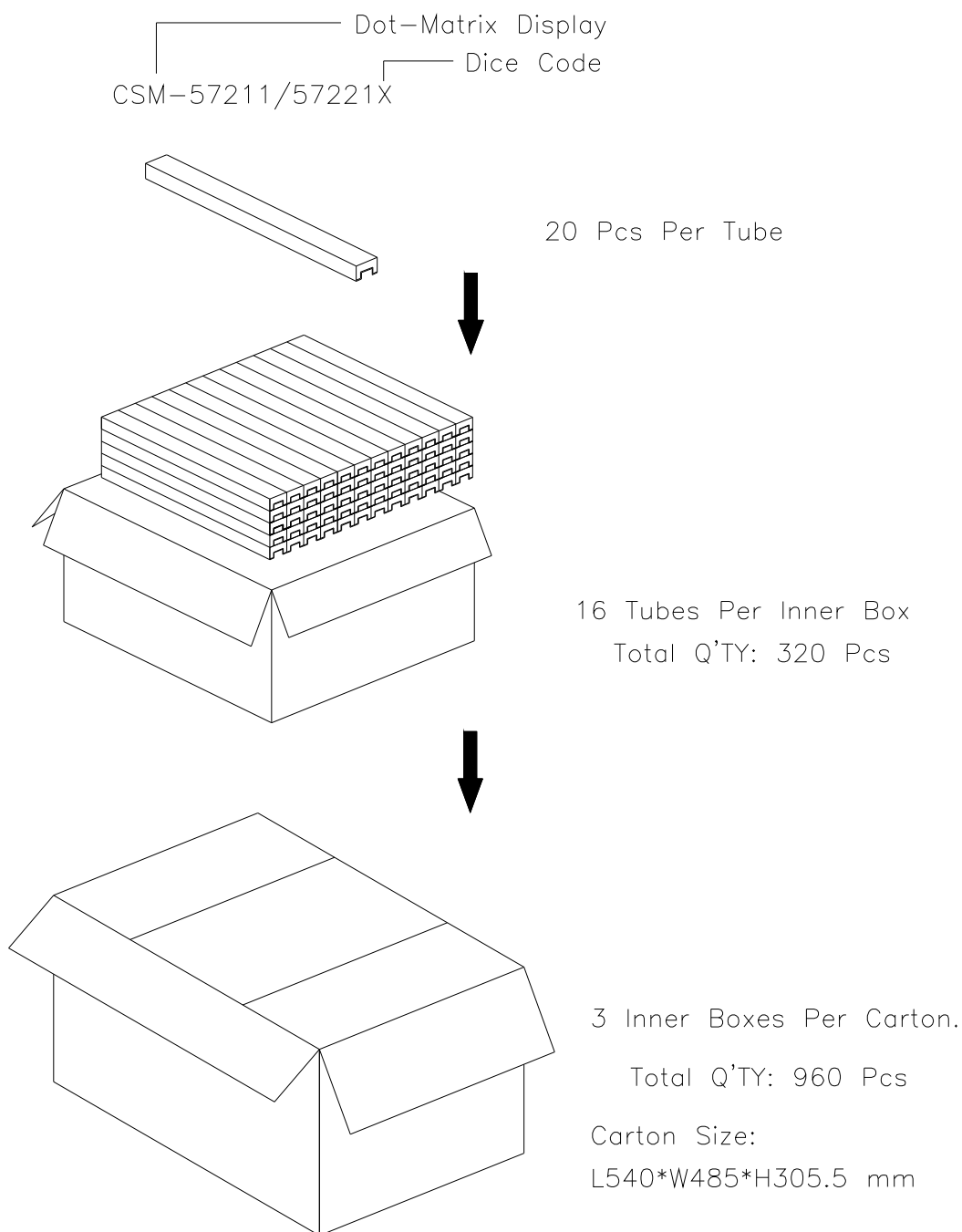
Fig.6 MAX PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE f=1 KHz)



Spec. No.	PS-ND-0710
Rev.	A

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■ Package Dimensions



Note: The specifications are subject to change without notice. Please contact us for updated information.